

TOSHIBA Transistor Silicon NPN Epitaxial Type

TPCP8507

High-Speed Switching Applications

DC/DC Converters

- High DC current gain: $h_{FE} = 120 \sim 300$ ($I_C = 0.1 \text{ A}$)
- Low collector-emitter saturation voltage: $V_{CE(sat)} = 0.14 \text{ V (max)}$
- High-speed switching: $t_f = 0.2 \mu\text{s}$ (typ.)

Absolute Maximum Ratings (Ta = 25°C)

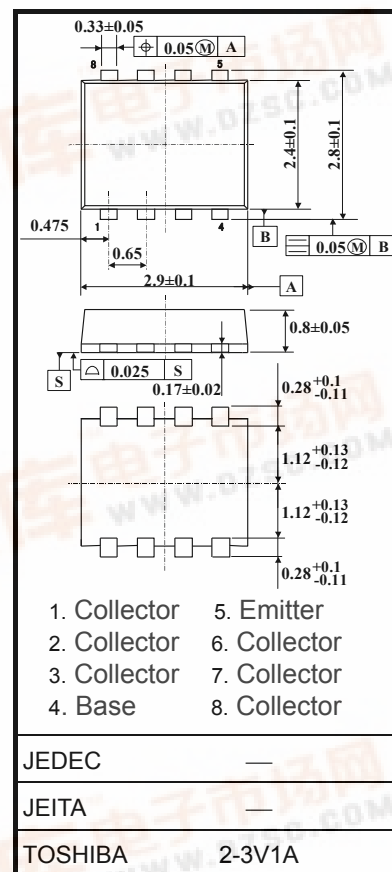
| Characteristic | | Symbol | Rating | Unit |
|-----------------------------|-----------------|----------------|---------|------|
| Collector-base voltage | | V_{CBO} | 180 | V |
| Collector-emitter voltage | | V_{CEX} | 150 | V |
| Collector-emitter voltage | | V_{CEO} | 120 | V |
| Collector-emitter voltage | | V_{EBO} | 7 | V |
| Collector current | DC (Note 1) | I_C | 1.0 | A |
| | Pulsed (Note 1) | I_{CP} | 2.0 | A |
| Base current | | I_B | 0.1 | A |
| Collector power dissipation | t = 10 s | P_C (Note 2) | 3.00 | W |
| | DC | | 1.25 | W |
| Junction temperature | | T_j | 150 | °C |
| Storage temperature range | | T_{stg} | -55~150 | °C |

Note 1: Ensure that the channel temperature does not exceed 150°C during use of the device.

Note 2: Mounted on an FR4 board (glass epoxy; 1.6 mm thick; Cu area, 645 mm²)

Note 3: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



Weight: 0.017 g (typ.)



Figure 1. Circuit configuration (top view)

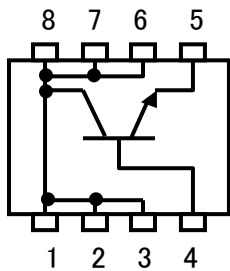
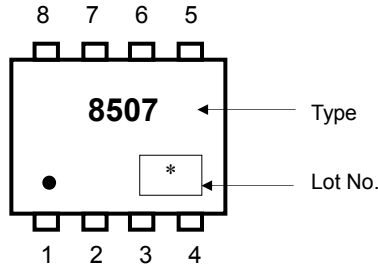
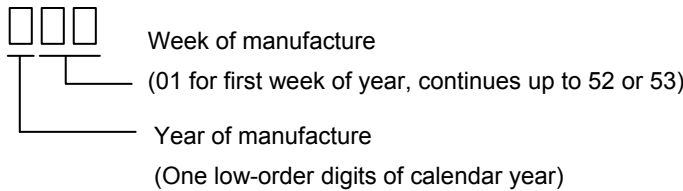


Figure 2. Marking (Note 4)



Note 4: ● on lower left of the marking indicates Pin 1.

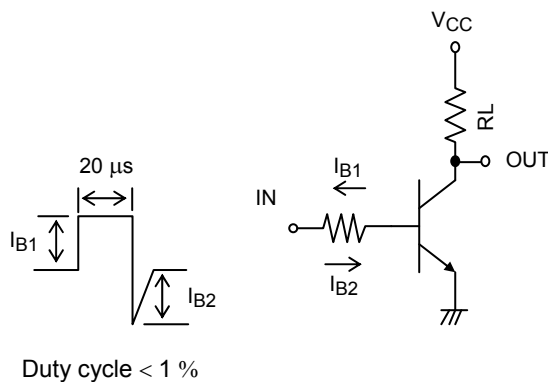
* Weekly code: (Three digits)

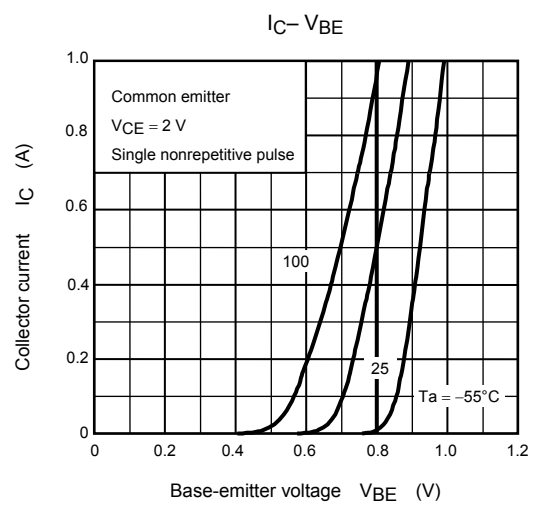
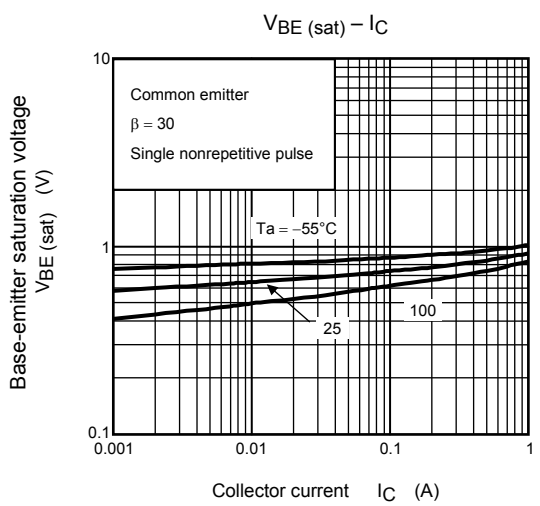
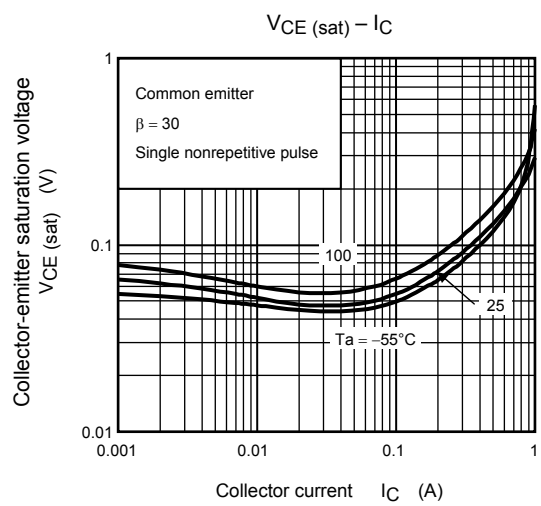
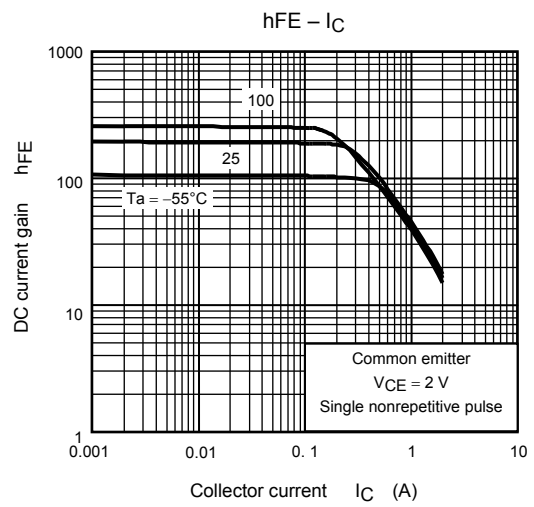
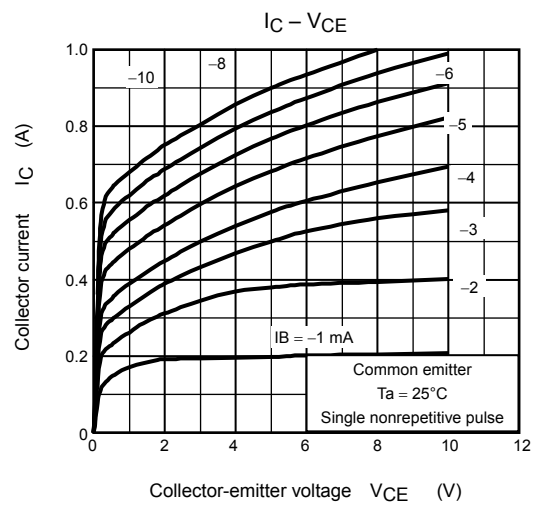


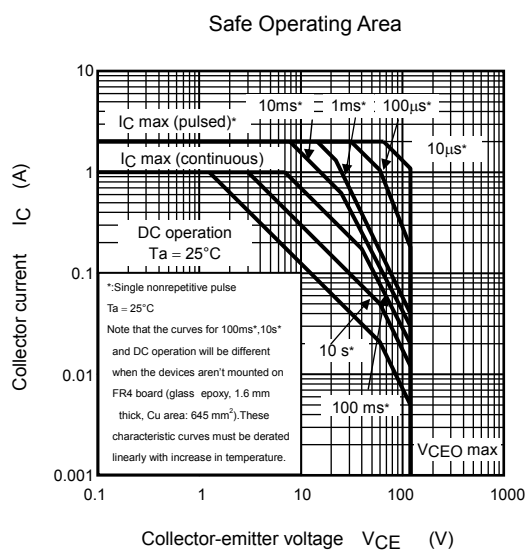
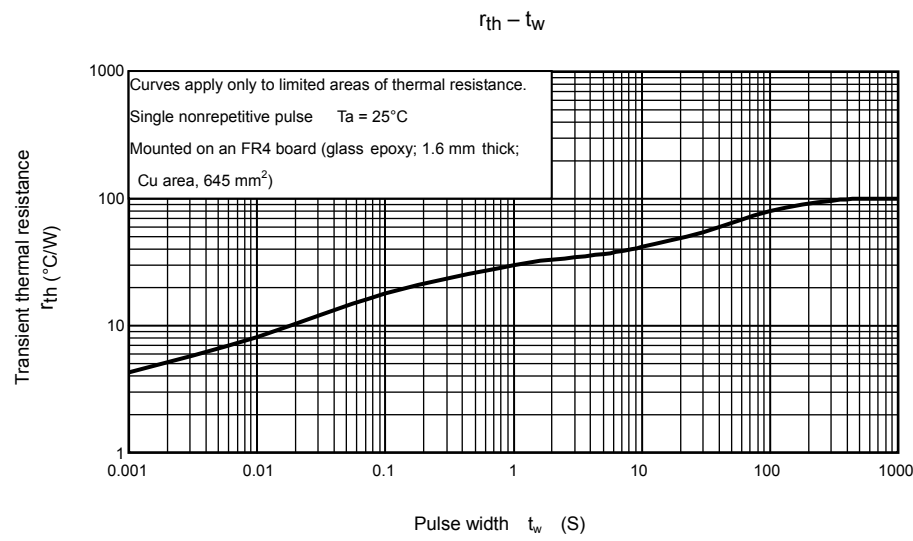
Electrical Characteristics (Ta = 25°C)

| Characteristic | | Symbol | Test Condition | Min | Typ. | Max | Unit |
|--------------------------------------|--------------|----------------|---|-----|------|------|---------------|
| Collector cutoff current | | I_{CBO} | $V_{CB} = 180\text{ V}, I_E = 0$ | — | — | 100 | nA |
| Emitter cutoff current | | I_{EBO} | $V_{EB} = 7\text{ V}, I_C = 0$ | — | — | 100 | nA |
| Collector-emitter breakdown voltage | | $V_{(BR) CBO}$ | $I_C = 1\text{ mA}, I_B = 0$ | 180 | — | — | V |
| Collector-emitter breakdown voltage | | $V_{(BR) CEO}$ | $I_C = 10\text{ mA}, I_B = 0$ | 120 | — | — | V |
| DC current gain | | $h_{FE(1)}$ | $V_{CE} = 2\text{ V}, I_C = 0.1\text{ A}$ | 120 | — | 300 | |
| | | $h_{FE(2)}$ | $V_{CE} = 2\text{ V}, I_C = 0.3\text{ A}$ | 60 | — | — | |
| Collector-emitter saturation voltage | | $V_{CE(sat)}$ | $I_C = 0.3\text{ A}, I_B = 0.01\text{ A}$ | — | — | 0.14 | V |
| Base-emitter saturation voltage | | $V_{BE(sat)}$ | $I_C = 0.3\text{ A}, I_B = 0.01\text{ A}$ | — | — | 1.1 | V |
| Switching time | Storage time | t_r | See Figure 3 circuit diagram. $V_{CC} \cong 72\text{ V}, R_L = 240\ \Omega$ $I_{B1} = -I_{B2} = 10\text{ mA}$ | — | 0.1 | — | μs |
| | Storage time | t_{stg} | | — | 1.5 | — | |
| | Fall time | t_f | | — | 0.2 | — | |

Figure 3. Switching Time Test Circuit & Timing Chart







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20070701-EN

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